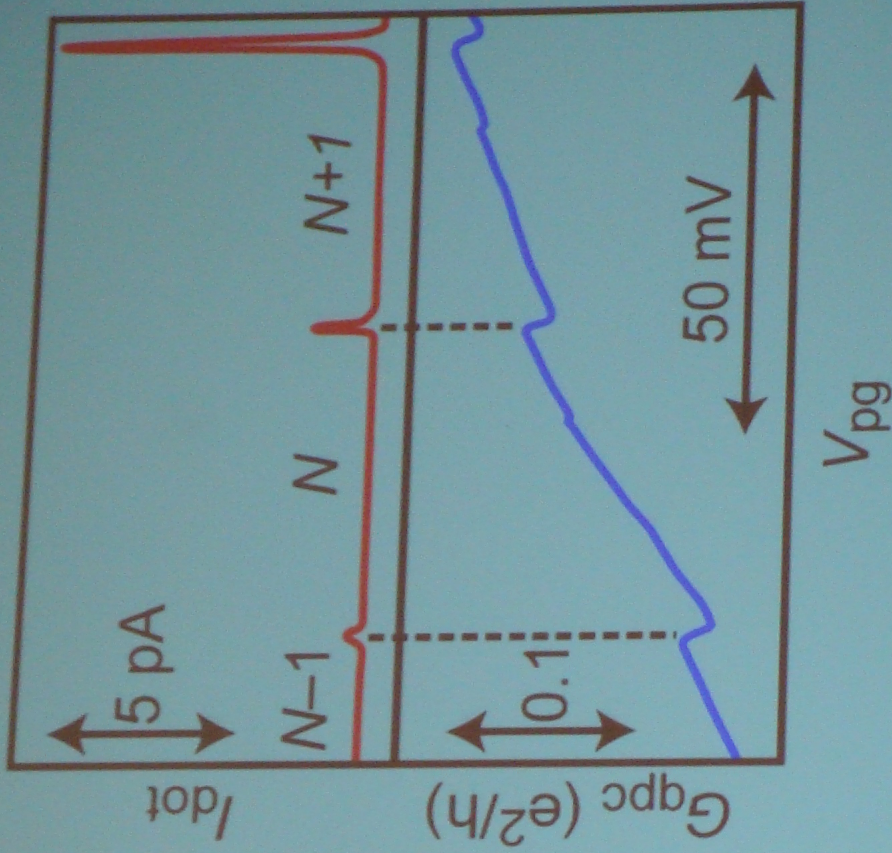
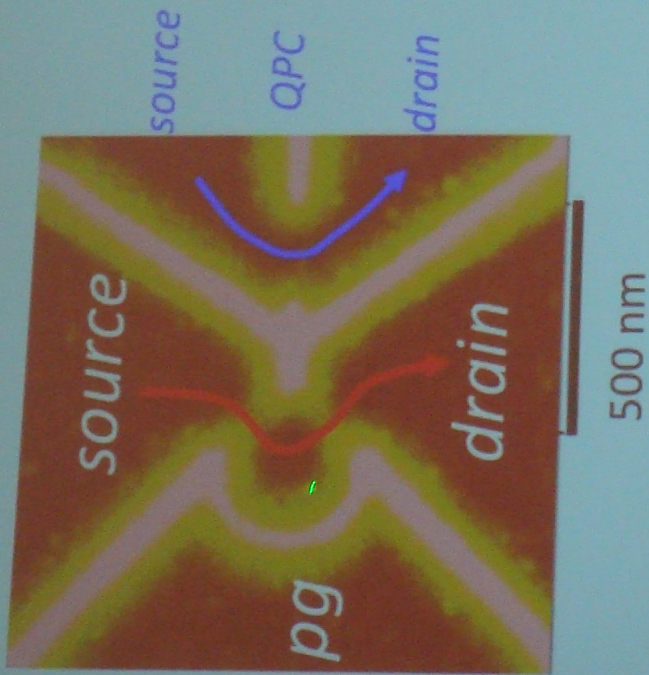


# Charge detection: an implementation

Ga[Al]As heterostructure

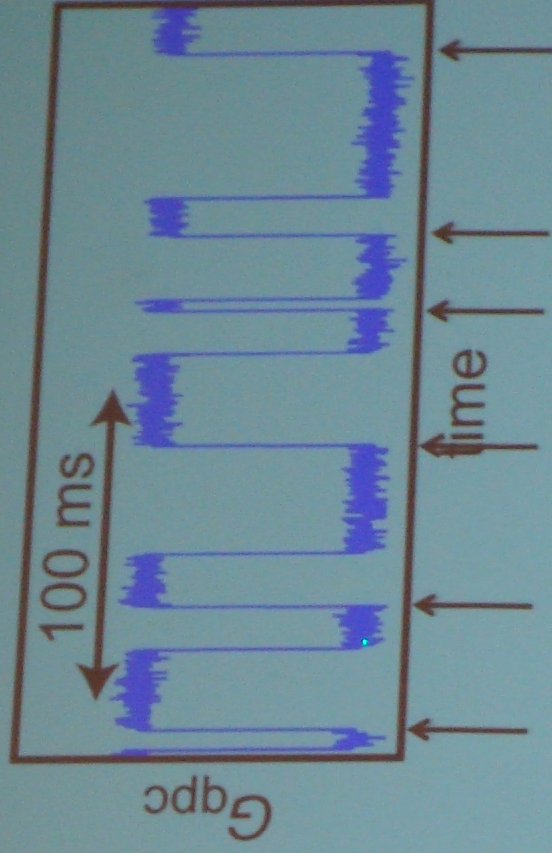
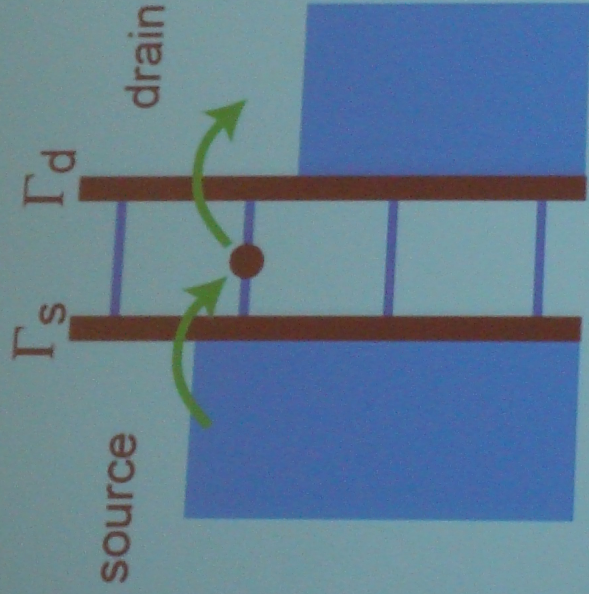


See for example:

- Field *et al.*, PRL **70**, 13111 (1993)
- Buks *et al.*, Nature **391**, 971 (1998)



# How and what we count



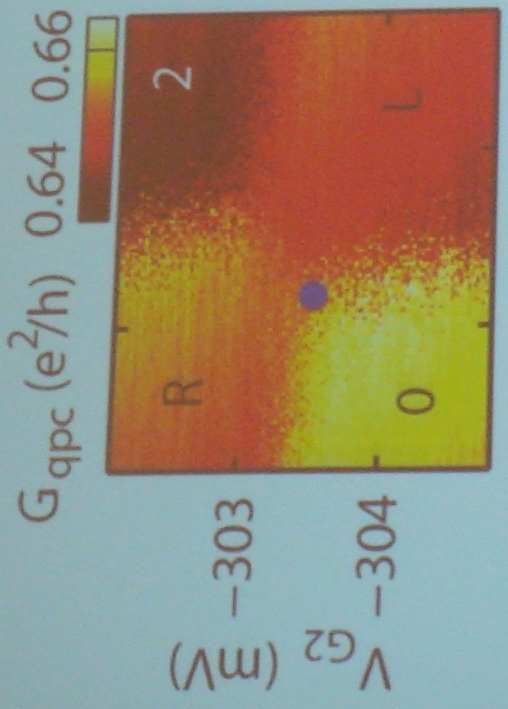
**Count:** One electron leaves the quantum dot

**Number of Counts per time interval:** Full counting statistics

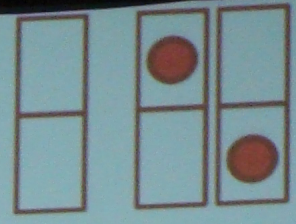
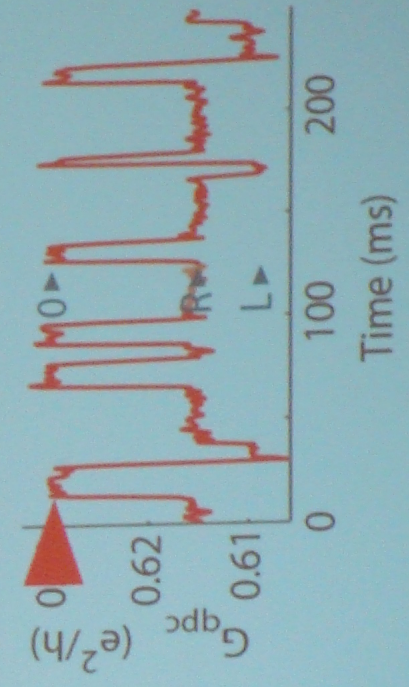
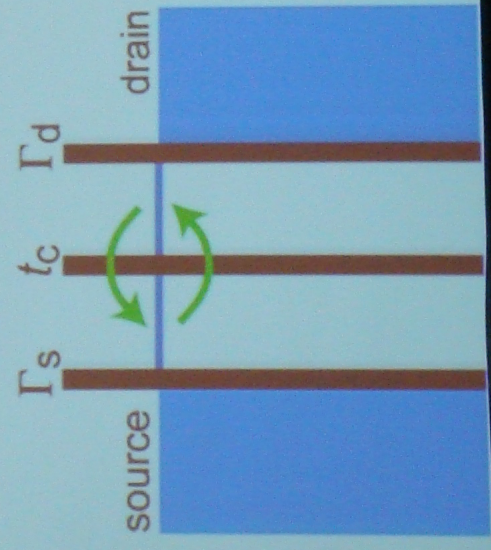
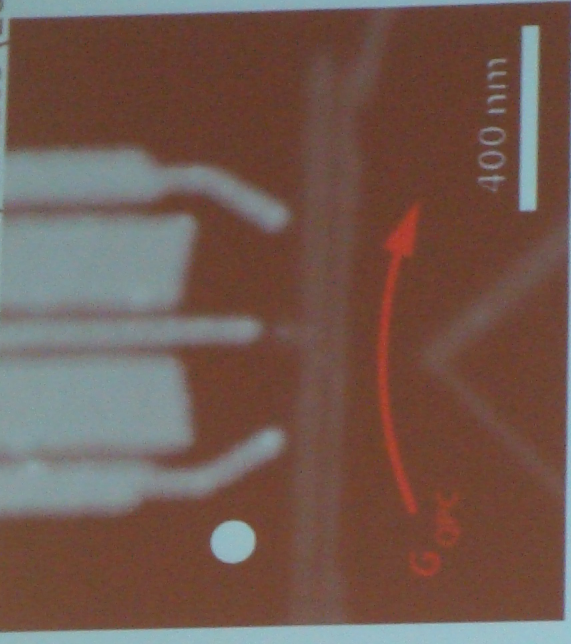
Measurements in the single-level transport regime



# Charge detection in double quantum dots: an implementation



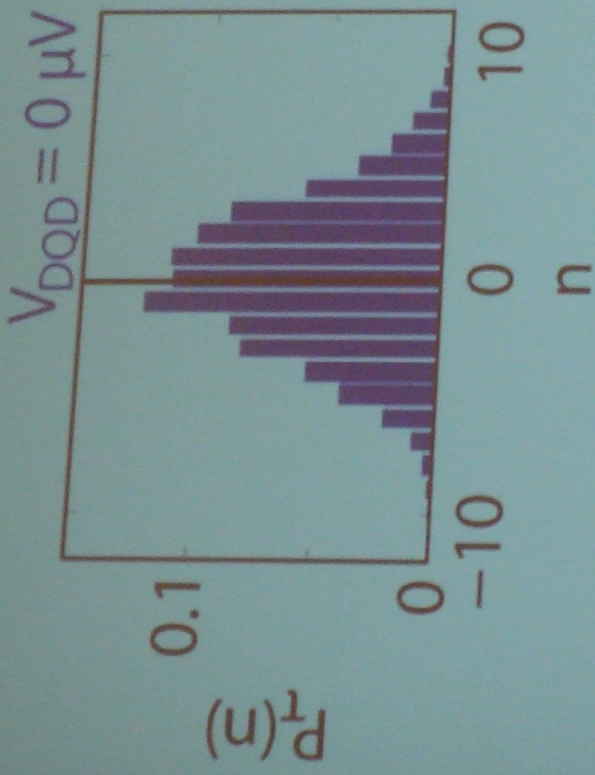
C. Rössler et al, APL 97, 152109 (2010)



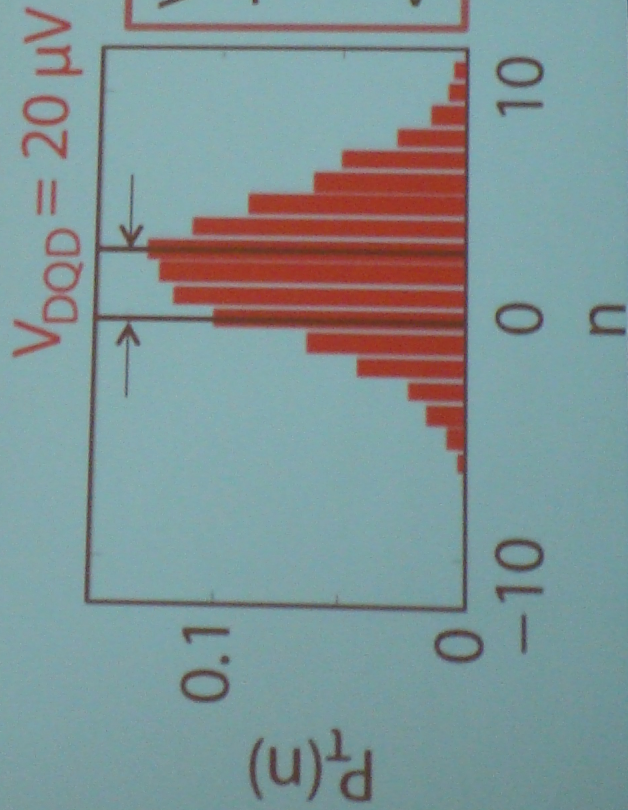
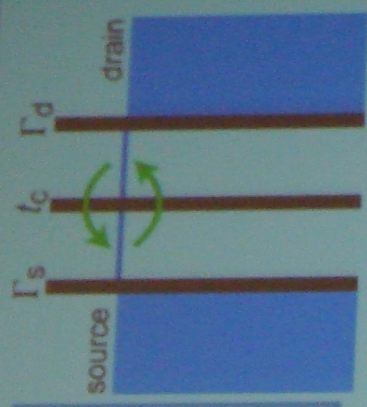
see also: T. Fujisawa et al, Science 312, 5780 (2006)



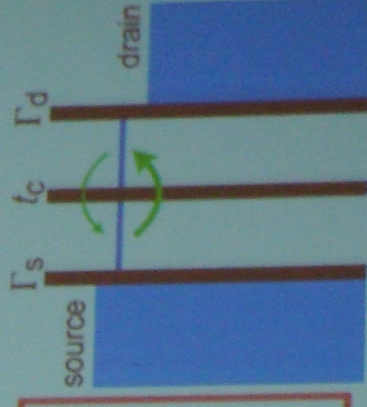
# Full counting statistics of the current



$V_{DQD} = 0 \mu\text{V}$   
 → no net charge flow  
 $\langle n \rangle = 0.09 \pm 0.09$



$V_{DQD} = 20 \mu\text{V}$   
 → finite charge flow  
 $\langle n \rangle = 2.39 \pm 0.09$

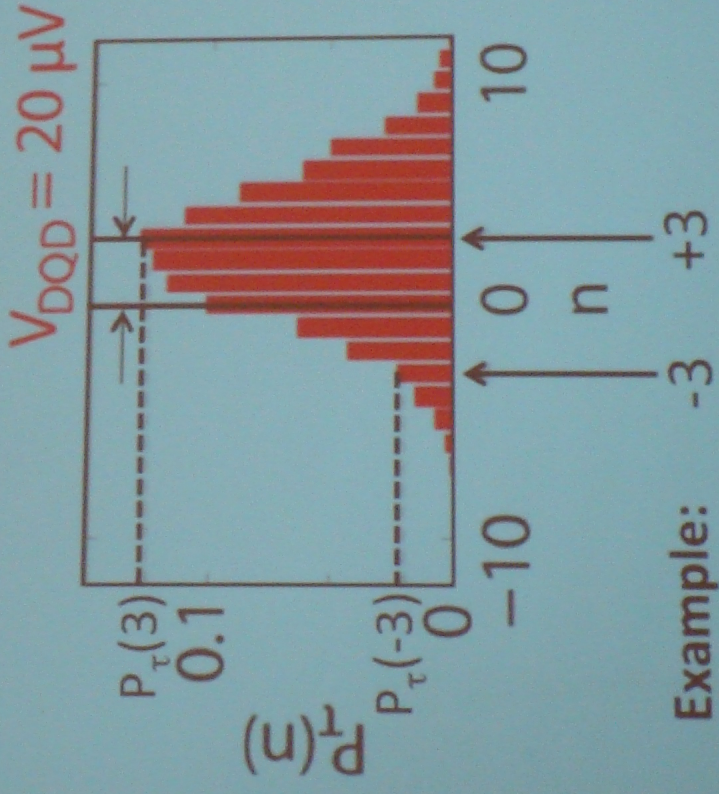




# Fluctuation theorem...

## ...and full counting statistics

$$\frac{P_\tau(\Delta S)}{P_\tau(-\Delta S)} = \exp\left(\frac{\Delta S}{k_B}\right) \Rightarrow \frac{P_\tau(n)}{P_\tau(-n)} = \exp\left(\frac{neV}{k_B T}\right)$$



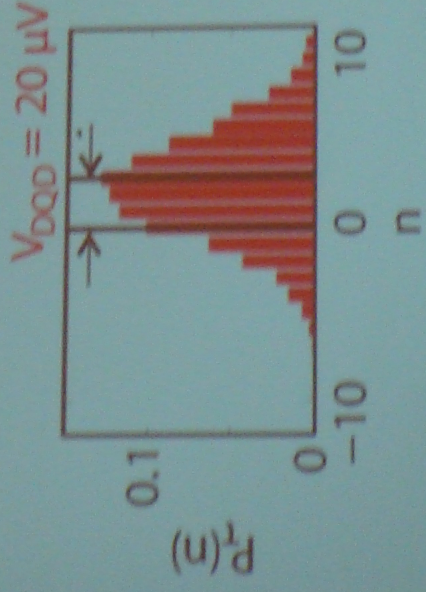
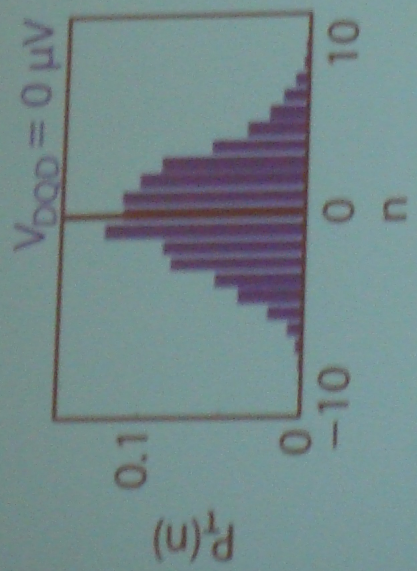
n: number of charges transferred from source to drain

see also: Y. Utsumi et al, PRB **81**, 125331 (2010)



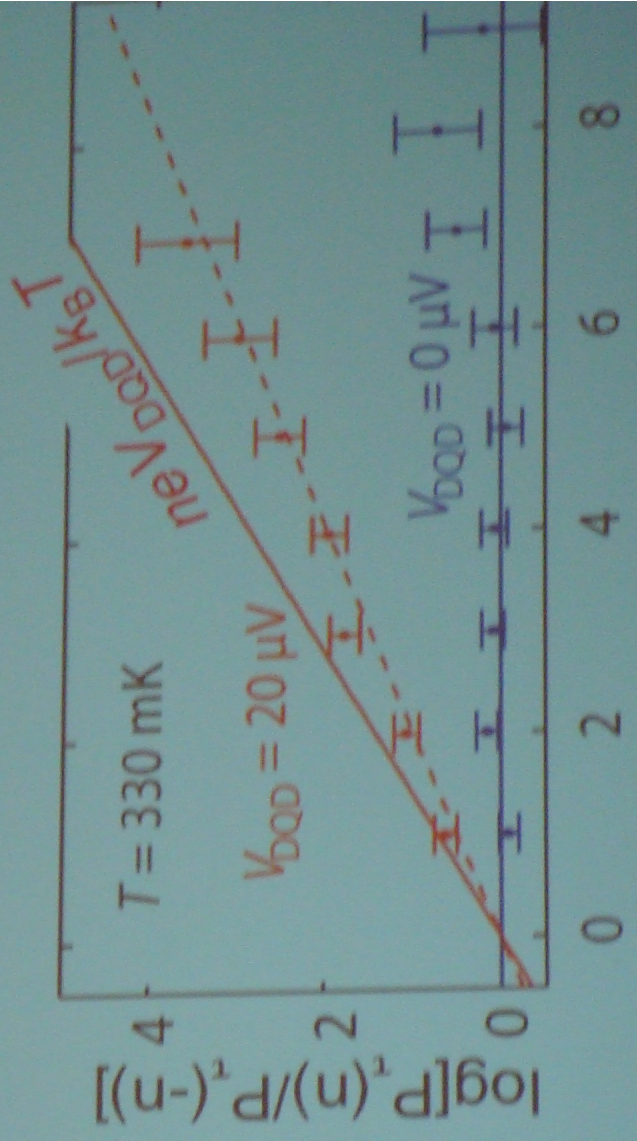
# Experimental test...

...of the fluctuation theorem



$$\frac{P_T(n)}{P_T(-n)} = \exp\left(\frac{neV_{DQD}}{k_B T}\right)$$

B. Kūng et al, PRX 2, 011001 (2012).



slope about 30% smaller than expected from theory (solid line)



# Summary

Full counting statistics in single quantum dots

S. Gustavsson *et al*, PRL **96**, 076605 (2006)

Bidirectional electron counting with a DQD

First quantitative test of fluctuation theorem in a mesoscopic conductor

- low and high bias
- different temperatures

B. Küng *et al*, PRX **2**, 011001 (2012).

